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July 2010

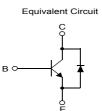
# **FJD5304D High Voltage Fast Switching Transistor**

#### **Features**

- · Built-in Free Wheeling Diode
- · Wide Safe Operating Area
- · Small Variance in Storage Time
- · Suitable for Electronic Ballast Application



1. Base 2. Collector 3. Emitter



## **Absolute Maximum Ratings** $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector-Base Voltage	700	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V	
V <sub>EBO</sub>	Emitter-Base Voltage	12	V	
I <sub>C</sub>	Collector Current (DC)	4	Α	
I <sub>CP</sub>	* Collector Current (Pulse)	8	Α	
I <sub>B</sub>	Base Current (DC)	2	Α	
I <sub>BP</sub>	* Base Current (Pulse)	4	Α	
P <sub>C</sub>	Collector Dissipation $T_c = 25^{\circ}C$ $T_a = 25^{\circ}C$	30 1.25	W W	
T <sub>J</sub>	Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature	-55 to 150	°C	

<sup>\*</sup> Pulse Test: PW = 300µs, Duty Cycle = 2% Pulsed

## **Thermal Characteristics** $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
$R_{\theta ja}$	Thermal Resistance Junction-Ambient **	99	°C/W

<sup>\*\*</sup> Device mounted on minimum pad size.

### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
J5304D	FJD5304DTM	D-PAK	13" Dia	-	2500
J5304D	FJD5304DTF	D-PAK	13" Dia	-	2000

## **Electrical Characteristics** $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 1mA, I <sub>E</sub> = 0	700			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 5mA$ , $I_B = 0$	400			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 1 \text{mA}, I_C = 0$	12			V
I <sub>CES</sub>	Collector Cut-off Current	V <sub>CB</sub> = 700V, I <sub>E</sub> = 0			100	μΑ
I <sub>CEO</sub>	Collector Cut-off Current	V <sub>CB</sub> = 400V, I <sub>B</sub> = 0			250	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = 12V, I <sub>C</sub> = 0			1	mA
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 10mA$ $V_{CE} = 5V, I_{C} = 2.0A$	10 8		40	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_C = 0.5A, I_B = 0.1A$			0.7	V
		I <sub>C</sub> = 1.0A, I <sub>B</sub> = 0.2A			1.0	V
		$I_C = 2.5A, I_B = 0.5A$			1.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_C = 0.5A, I_B = 0.1A$			1.1	V
		I <sub>C</sub> = 1.0A, I <sub>B</sub> = 0.2A			1.2	V
		$I_C = 2.5A, I_B = 0.5A$			1.3	V
t <sub>STG</sub>	Storage Time	V <sub>CLAMP</sub> =200V, I <sub>C</sub> =2.0A,		0.6		μS
t <sub>F</sub>	Fall Time	$I_{B1}$ =0.4A, $V_{BE}$ (off)=-5V, L=200 $\mu$ H		0.1		μS
t <sub>STG</sub>	Storage Time	V <sub>CC</sub> =250V, I <sub>C</sub> =2.0A,			2.9	μS
t <sub>F</sub>	Fall Time	I <sub>B1</sub> =0.4A, I <sub>B2</sub> =-0.4A, T <sub>P</sub> =30μs		0.2		μS
V <sub>F</sub>	Diode Forward Voltage	I <sub>F</sub> = 2A			2.5	V

#### **Typical Performance Characteristics**

Figure 1. Static Characteristic

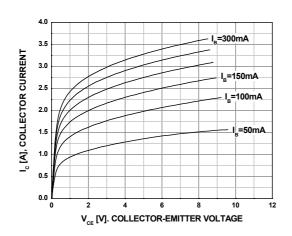


Figure 2. DC Current Gain

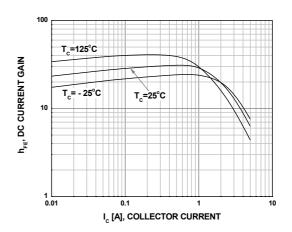


Figure 3. Collector-Emitter Saturation Voltage

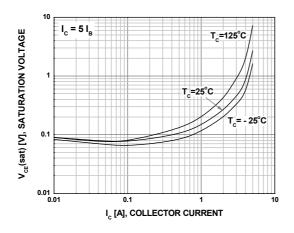


Figure 4. Base-Emitter Saturation Voltage

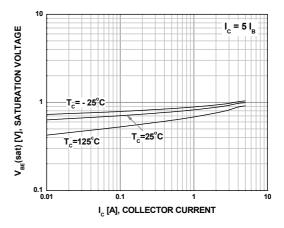


Figure 5. Resistive Load Switching Time

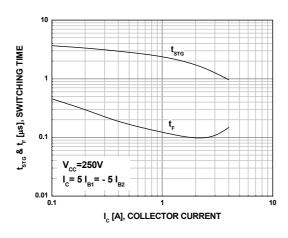
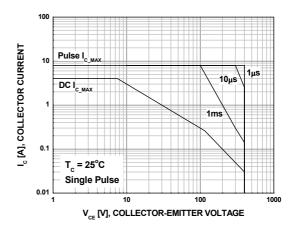


Figure 6. Forward Biased Safe Operating Area



### **Typical Performance Characteristics** (Continued)

Figure 7. Reverse Biased Safe Operating Area

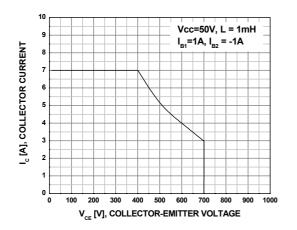
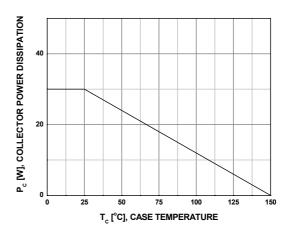
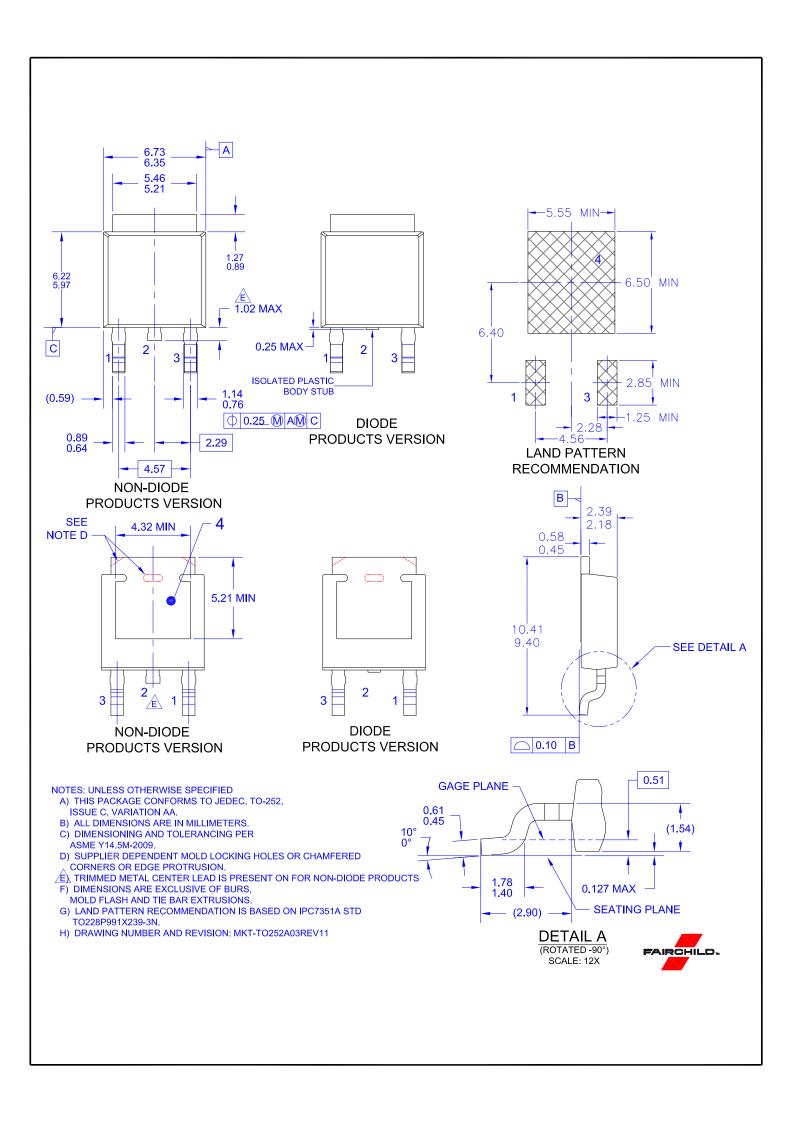


Figure 8. Power Derating Curve





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